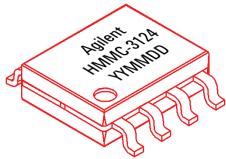


# Agilent HMMC-3124 DC-12 GHz Packaged High Efficiency Divide-by-4 Prescaler

1GC1-8207-TR1-7" diameter reel/500 each 1GC1-8207-BLK-bubble strip/10 each

## Data Sheet



Package Type:
Package Dimensions:
Package Thickness:
Lead Pitch:
Lead Width:

8-lead SOIC Plastic
4.9 x 3.9 mm typ.
1.55 mm typ.
1.25 mm nom.
0.42 mm nom.

### **Features**

- Wide Frequency Range: 0.2-12 GHz
- High Input Power Sensitivity: On-chip pre- and post-amps
  - -15 to +10 dBm (1-8 GHz) -10 to +8 dBm (8-10 GHz)
  - -5 to +2 dBm (10-12 GHz)
- P<sub>out</sub>: 0 dBm (0.5 V<sub>p-p</sub>)
- · Low Phase Noise:
  - -153 dBc/Hz @ 100 kHz Offset
- (+) or (-) Single Supply Bias Operation
- Wide Bias Supply Range:
   4.5 to 6.5 volt operating range
- Differential I/O with on-chip 50  $\Omega$  matching

# **Description**

The HMMC-3124 is a packaged GaAs HBT MMIC prescaler which offers dc to 12 GHz frequency translation for use in communications and EW systems incorporating high-frequency PLL oscillator circuits and signal-path down conversion applications. The prescaler provides a large input power sensitivity window and low phase noise.

# Absolute Maximum Ratings<sup>1</sup>

(@  $T_A = 25$ °C, unless otherwise indicated)

Symbol	Parameters/Conditions	Min.	Max.	Units
V <sub>CC</sub>	Bias supply voltage		+7	volts
V <sub>EE</sub>	Bias supply voltage	-7		volts
V <sub>CC</sub> - V <sub>EE</sub>	Bias supply delta	0	+7	volts
V <sub>Logic</sub>	Logic threshold voltage	V <sub>CC</sub> -1.5	V <sub>CC</sub> -1.2	volts
P <sub>in(CW)</sub>	CW RF input power		+10	dBm
V <sub>RFin</sub>	DC input voltage (@ RF <sub>in</sub> or RF <sub>in</sub> ports)		V <sub>CC</sub> ±0.5	volts
$T_{BS}^2$	Backside operating temperature	-40	+85	°C
T <sub>st</sub>	Storage temperature	-65	+165	°C
T <sub>max</sub>	Maximum assembly temperature (60 s max.)		310	°C

#### Notes

- 1. Operation in excess of any parameter limit (except T<sub>BS</sub>) may cause permanent damage to the device.
- 2. MTTF > 1 x  $10^6$  hours @  $T_{BS} \le 85^\circ C$ . Operation in excess of maximum operating temperature ( $T_{BS}$ ) will degrade MTTF.



DC Specifications/Physical Properties ( $T_A = 25^{\circ}\text{C}$ ,  $V_{CC} - V_{EE} = 5.0$  volts, unless otherwise listed)

Symbol	Parameters/Conditions	Min.	Тур.	Max.	Units
$\overline{V_{CC} - V_{EE}}$	Operating bias supply difference <sup>1</sup>	4.5	5.0	6.5	volts
I <sub>CC</sub>   or  I <sub>EE</sub>	Bias supply current	34	40	46	mA
V <sub>RFin(q)</sub>	Quiescent dc voltage appearing at all RF ports		V <sub>CC</sub>		volts
V <sub>Logic</sub>	Nominal ECL Logic Level (V <sub>Logic</sub> contact self-bias voltage, generated on-chip)	V <sub>CC</sub> -1.45	V <sub>CC</sub> -1.32	V <sub>CC</sub> -1.25	volts

#### Notes

**RF Specifications** (T<sub>A</sub> = 25°C, Z<sub>0</sub> = 50  $\Omega$ , V<sub>CC</sub> – V<sub>EE</sub> = 5.0 volts)

Units	Max.	Тур.	Min.	Parameters/Conditions	Symbol
GHz		14	12	Maximum input frequency of operation	$\overline{f_{\text{in(max)}}}$
GHz	0.5	0.2		Minimum input frequency of operation <sup>1</sup> (P <sub>in</sub> = -10 dBm)	$f_{in(min)}$
GHz		3.4		Output Self-Oscillation Frequency <sup>2</sup>	$f_{Self-Osc.}$
dBm	+10	> -25	-15	@ dc, (Square-wave input)	P <sub>in</sub>
dBm	+10	> -20	-15	@ $f_{in}$ = 500 MHz, (Sine-wave input)	
dBm	+10	> -20	-15	$f_{in}$ = 1 to 8 GHz	
dBm	+5	> -15	-10	f <sub>in</sub> = 8 to 10 GHz	
dBm	+1	> -10	-5	f <sub>in</sub> = 10 to 12 GHz	
dB		Small-Signal Input/Output Return Loss (@ $f_{in}$ < 10 GHz) 15		RL	
dB		Small-Signal Reverse Isolation (@ $f_{in}$ < 10 GHz)		S <sub>12</sub>	
dBc/Hz	SSB Phase noise (@ $P_{in}$ = 0 dBm, 100 kHz offset from a -153 $f_{out}$ = 1.2 GHz Carrier)		ΦΝ		
ps		Input signal time variation @ zero-crossing 1 $(f_{in} = 10 \text{ GHz}, P_{in} = -10 \text{ dBm})$		Jitter	
ps		70		Output transition time (10% to 90% rise/fall time)	T <sub>r</sub> or T <sub>f</sub>
_		-153 1	n a	SSB Phase noise (@ $P_{in} = 0$ dBm, 100 kHz offset from $f_{out} = 1.2$ GHz Carrier)  Input signal time variation @ zero-crossing ( $f_{in} = 10$ GHz, $P_{in} = -10$ dBm)	Jitter

<sup>1.</sup> Prescaler will operate over full specified supply voltage range, V<sub>CC</sub> or V<sub>EE</sub> not to exceed limits specified in Absolute Maximum Ratings section.

<sup>1.</sup> For sine-wave input signal. Prescaler will operate down to dc for square-wave input signal. Minimum divide frequency limited by input slew-rate.

<sup>2.</sup> Prescaler may exhibit this output signal under bias in the absence of an RF input signal. This condition may be eliminated by use of the Input dc offset technique described on page 4.

# **RF Specifications** (Continued)

 $(T_A = 25^{\circ}C, Z_0 = 50 \Omega, V_{CC} - V_{EE} = 5.0 \text{ volts})$ 

Symbol	Parameters/Conditions	Min.	Тур.	Max.	Units
P <sub>out</sub> <sup>3</sup>	@ f <sub>out</sub> < 1 GHz	-2	0		dBm
	@ f <sub>out</sub> = 2.5 GHz	-3.5	-1.5		dBm
	@ f <sub>out</sub> = 3.0 GHz	-4.5	-2.5		dBm
V <sub>out(p-p)</sub>   <sup>4</sup>	$ @  f_{out} < 1 \; GHz $		0.5		volts
	@ f <sub>out</sub> = 2.5 GHz		0.42		volts
	@ $f_{\text{out}} = 3.0 \text{ GHz}$		0.37		volts
P <sub>Spitback</sub>	$f_{ m out}$ power level appearing at RF <sub>in</sub> or $\overline{ m RF}_{ m in}$ (@ $f_{ m in}$ 10 GHz, unused RF <sub>out</sub> or $\overline{ m RF}_{ m out}$ unterminated)		-50		dBm
	$f_{\text{out}}$ power level appearing at $\overline{\text{RF}}_{\text{in}}$ or $\overline{\text{RF}}_{\text{in}}$ (@ $f_{\text{in}}$ = 10 GHz, both RF <sub>out</sub> & $\overline{\text{RF}}_{\text{out}}$ terminated)		-55		dBm
P <sub>feedthru</sub>	Power level of $f_{in}$ appearing at RF <sub>out</sub> or $\overline{\text{RF}}_{\text{out}}$ (@ $f_{in}$ = 12 GHz, $P_{in}$ = 0 dBm, referred to $P_{in}$ ( $f_{in}$ ))		-30		dBc
H <sub>2</sub>	Second harmonic distortion output level (@ $f_{out} = 3.0$ GHz, referred to $P_{out}(f_{out})$ )		-25		dBc

#### Notes

- 3. Fundamental of output square wave's Fourier Series.
- 4. Square wave amplitude calculated from Pout-

## **Applications**

The HMMC-3124 is designed for use in high frequency communications, microwave instrumentation, and EW radar systems where low phase-noise PLL control circuitry or broad-band frequency translation is required.

### **Operation**

The device is designed to operate when driven with either a single-ended or differential sinusoidal input signal over a 200 MHz to 12 GHz bandwidth. Below 200 MHz the prescaler input is "slew-rate" limited, requiring fast rising and falling edge speeds to properly divide. The device will operate at frequencies down to dc when driven with a square-wave.

Due to the presence of an off-chip RF-bypass capacitor inside the package (connected to the  $V_{CC}$  contact on the device), and the unique design of the device itself, the component may be biased from either a single positive or single negative supply bias. The backside of the package is not dc connected to any dc bias point on the device.

For positive supply operation,  $V_{CC}$  pins are nominally biased at any voltage in the +4.5 to +6.5 volt range with pin 8 ( $V_{EE}$ ) grounded. For negative bias operation  $V_{CC}$  pins are typically grounded and a negative voltage between -4.5 to -6.5 volts is applied to pin 8 ( $V_{FE}$ ).

# **AC-Coupling and DC-Blocking**

All RF ports are dc connected on-chip to the V<sub>CC</sub> contact through on-chip 50  $\Omega$  resistors. Under any bias conditions where  $V_{CC}$  is not dc grounded the RF ports should be ac coupled via series capacitors mounted on the PC board at each RF port. Only under bias conditions where V<sub>CC</sub> is dc grounded (as is typical for negative bias supply operation) may the RF ports be direct coupled to adjacent circuitry or in some cases, such as level shifting to subsequent stages. In the latter case the package heat sink may be "floated" and bias applied as the difference between V<sub>CC</sub> and V<sub>FF</sub>.

# **Input DC Offset**

If an RF signal with sufficient signal to noise ratio is present at the RF input lead, the prescaler will operate and provide a divided output equal the input frequency divided by the divide modulus. Under certain "ideal" conditions where the input is well matched at the right input frequency, the component may "self-oscillate", especially under small signal input powers or with only noise present at the input. This "self-oscillation" will produce a undesired output signal also known as a false trigger. To prevent false triggers or self-oscillation conditions, apply a 20 to 100 mV dc offset voltage between the RF<sub>in</sub> and RF<sub>in</sub> ports. This prevents noise or spurious low level signals from triggering the divider.

Adding a 10  $k\Omega$  resistor between the unused RF input to a contact point at the  $V_{EE}$  potential will result in an offset of  $\approx 25$  mV between the RF inputs. Note however, that the input sensitivity will be reduced slightly due to the presence of this offset.

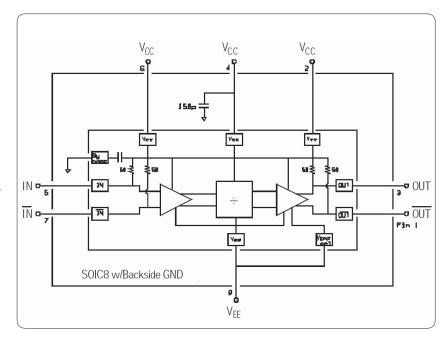


Figure 1. Simplified Schematic

# **Assembly Notes**

Independent of the bias applied to the package, the backside of the package should always be connected to both a good RF ground plane and a good thermal heat sinking region on the PC board to optimize performance. For single-ended output operation the unused RF output lead should be terminated into 50  $\Omega$  to a contact point at the  $V_{\rm CC}$  potential or to RF ground through a dc blocking capacitor.

A minimum RF and thermal PC board contact area equal to or greater than  $2.67 \times 1.65$  mm  $(0.105" \times 0.065")$  with eight 0.020" diameter plated-wall thermal vias is recommended.

MMIC ESD precautions, handling considerations, die attach and bonding methods are critical factors in successful GaAs MMIC performance and reliability.

Agilent application note #54, "GaAs MMIC ESD, Die Attach and Bonding Guidelines" provides basic information on these subjects.

Moisture Sensitivity Classification: Class 1, per JESD22-A112-A.

#### Additional References:

PN #18, "HBT Prescaler Evaluation Board."

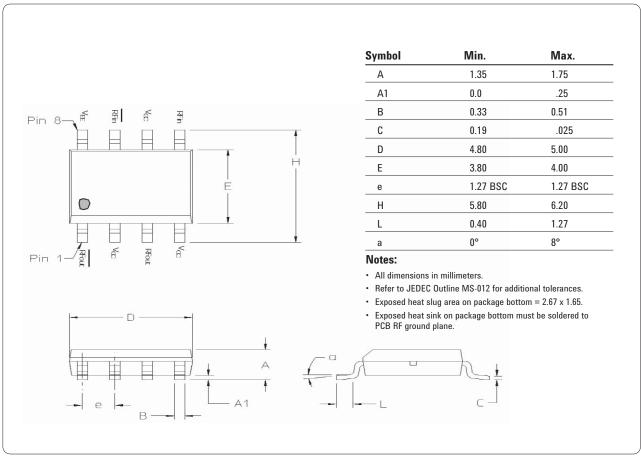


Figure 2. Package and dimensions

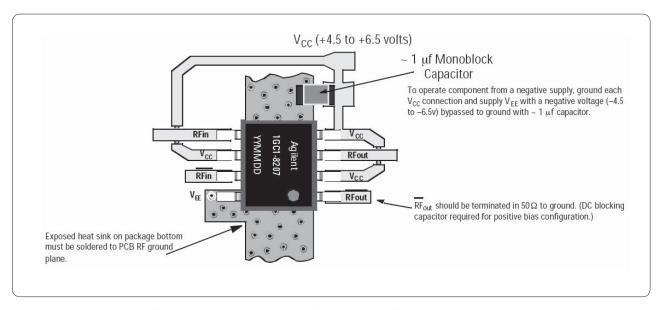


Figure 3. Assembly diagram (Single-supply, positive-bias configuration shown)

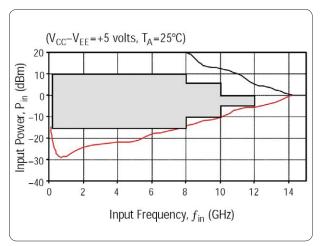


Figure 4. Typical input sensitivity window

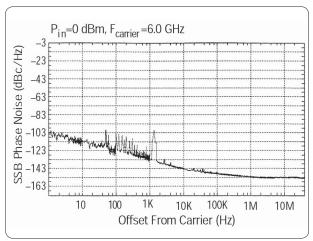


Figure 6. Typical phase noise performance

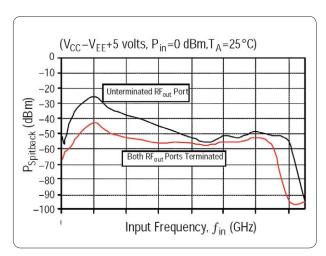


Figure 8. Typical "Spitback" power  $P(f_{out})$  appearing at RF input port

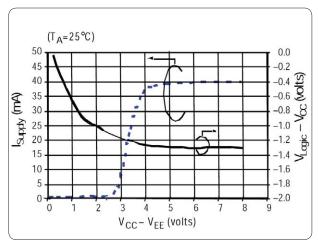


Figure 5. Typical supply current &  $V_{Logic}$  vs. supply voltage

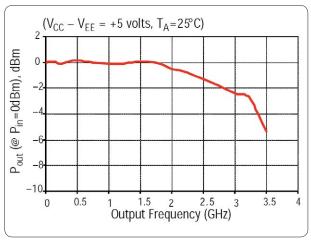
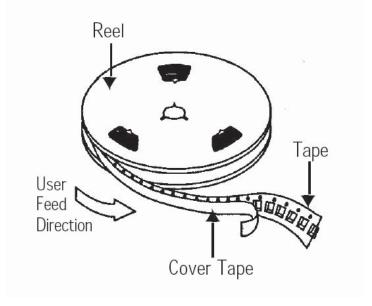
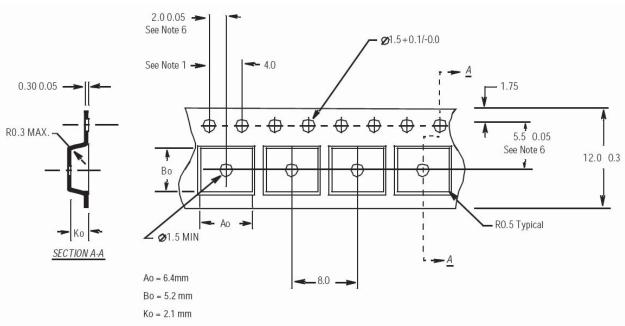


Figure 7. Typical output power vs. output frequency,  $f_{out}$  (GHz)

## **Device Orientation**



# **Tape Dimensions and Product Orientation**



#### Notes:

- 1.  $10 \ \text{sprocket}$  hole pitch cumulative tolerance:  $0.2 \ \text{mm}$ .
- 2. Camber not to exceed 1 mm in 100 mm.
- 3. Material: Black Conductive Advantek Polystyrene.
- 4. Ao and Bo measured on a plane 0.3 mm above the bottom of the pocket.
- 5. Ko measured from a plane on the inside bottom of the pocket to the top surface of the carrier.
- 6. Pocket position relative to sprocket hole measured as true position of pocket, not pocket hole.

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